



TLV600x-Q1 低コスト・システム用の低消費電力、レール・ツー・レール 入出力、1MHz のオペアンプ

1 特長

- 車載アプリケーション用にAEC-Q100認定済み
 - デバイス温度グレード 1: $-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$ 、 T_A
 - デバイスHBM ESD分類レベル3A
 - デバイスCDM ESD分類レベルC6
- 低コスト・システム用の汎用アンプ
- 電源電圧範囲: 1.8V~5.5V
- ゲイン帯域幅: 1MHz
- 低い静止電流: 75 $\mu\text{A}/\text{ch}$
- レール・ツー・レール入出力
- 低いオフセット電圧: 0.75mV
- ユニティ・ゲインで安定
- 入力電圧ノイズ密度: 1kHzにおいて28nV/ $\sqrt{\text{Hz}}$
- RF/EMIフィルタ内蔵
- 拡張温度範囲: $-40^{\circ}\text{C} \sim 125^{\circ}\text{C}$

2 アプリケーション

- AEC-Q100グレード1機器に対して最適化
- 電気自動車用インバータ
- インフォテインメント
- パッシブ・セーフティ
- ボディ・エレクトロニクスおよびライティング

3 概要

TLV600x-Q1 ファミリーはシングルおよびデュアル・チャネルのオペアンプで、汎用の車載アプリケーション向けに特化して設計されています。レール・ツー・レール入出力 (RRIO) スイング、低い静止電流 (標準値 75 μA)、広い帯域幅 (1MHz)、低いノイズ (1kHz において 28nV/ $\sqrt{\text{Hz}}$) という特長から、このファミリーはインフォテインメント、エンジン制御ユニット、車両用ライトなど、コストと性能の適切なバランスが必要な各種の車載アプリケーションに魅力的な選択肢です。入力バイアス電流が低い (標準値 $\pm 1\text{pA}$) ため、TLV600x-Q1 はソース・インピーダンスがメガオーム単位のアプリケーションに使用できます。

TLV600x-Q1 は堅牢に設計されており、150pF までの容量性負荷に対するユニティ・ゲイン安定性、RF/EMI 除去フィルタの搭載、オーバードライブ状態で位相反転が発生しない、高い静電放電 (ESD) 保護 (4kV HBM) といった特長があるため、回路設計が容易です。

これらのデバイスは、1.8V ($\pm 0.9\text{V}$)~5.5V ($\pm 2.75\text{V}$) の電圧で動作するよう最適化され、拡張温度範囲の $-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$ での動作が規定されています。

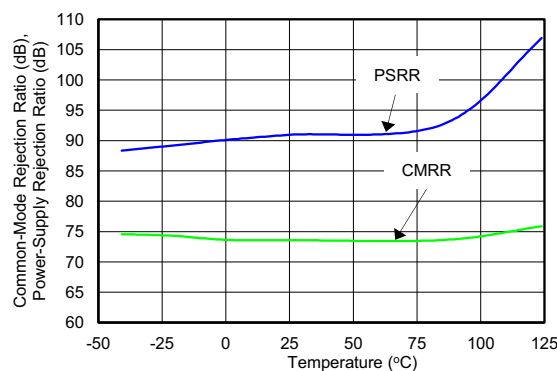
シングル・チャネルの TLV6001-Q1 は SC70-5 パッケージ、デュアル・チャネルの TLV6002-Q1 は SOIC と VSSOP の両方のパッケージで供給されます。

製品情報⁽¹⁾

型番	パッケージ	本体サイズ (公称)
TLV6001-Q1	SC70 (5)	2.00mm×1.25mm
TLV6002-Q1	SOIC (8)	3.91mm×4.90mm
	VSSOP (8)	3.00mm×3.00mm

(1) 提供されているすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

CMRRおよびPSRRと温度との関係



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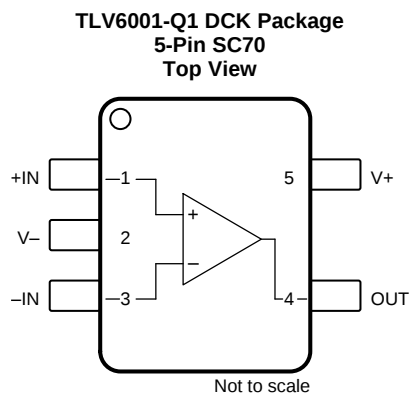
4 改訂履歴

2018年8月発行のものから更新

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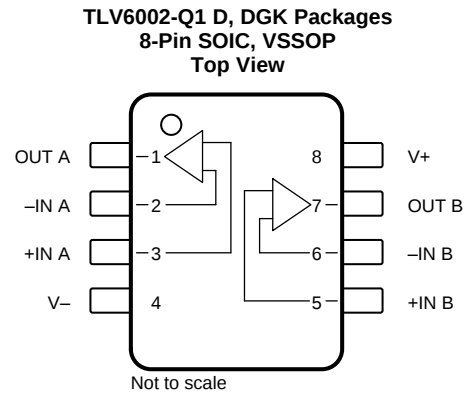
• データシートに TLV6002-Q1 デバイスを追加	1
• データシート全体で、TLV6002-Q1 デバイスのデュアル・チャネル情報を追加	1
• TLV600x-Q1 ファミリの ESD 分類レベルを追加	1

5 Pin Configuration and Functions



Pin Functions: TLV6001-Q1

PIN		I/O	DESCRIPTION
NAME	NO.		
-IN	3	I	Inverting input
+IN	1	I	Noninverting input
OUT	4	O	Output
V-	2	—	Negative (lowest) power supply
V+	5	—	Positive (highest) power supply


Pin Functions: TLV6002-Q1

PIN		I/O	DESCRIPTION
NAME	NO.		
-IN A	2	I	Inverting input, channel A
-IN B	6	I	Inverting input, channel B
+IN A	3	I	Noninverting input, channel A
+IN B	5	I	Noninverting input, channel B
OUT A	1	O	Output, channel A
OUT B	7	O	Output, channel B
V-	4	—	Negative (lowest) power supply
V+	8	—	Positive (highest) power supply

6 Specifications

6.1 Absolute Maximum Ratings

over recommended operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage	Supply voltage (V+) – (V–)		7	V
	Signal input pins, voltage ⁽²⁾	(V–) – 0.5	(V+) + 0.5	
Current	Signal input pins, current ⁽²⁾	–10	10	mA
	Output short-circuit ⁽³⁾	Continuous		
Temperature	Operating, T _A	–40	150	°C
	Junction, T _J		150	
	Storage, T _{stg}	–65	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.
- (3) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾ HBM ESD Classification Level 3A	±4000	V
	Charged-device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B	±1000	

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _S	Supply voltage	1.8	5.5	V
T _A	Specified temperature	–40	125	°C

6.4 Thermal Information: TLV6001-Q1

THERMAL METRIC ⁽¹⁾		TLV6001-Q1	UNIT
		DCK (SC70)	
		5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	281.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	91.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	59.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	1.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	58.8	°C/W

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

6.5 Thermal Information: TLV6002-Q1

THERMAL METRIC ⁽¹⁾		TLV6002-Q1		UNIT
		D (SOIC)	DGK (VSSOP)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	131.6	186.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	71.4	73.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	75.4	107.3	°C/W
ψ_{JT}	Junction-to-top characterization parameter	22.7	14.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	74.6	105.6	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.6 Electrical Characteristics: $V_S = 1.8\text{ V to }5\text{ V }(\pm 0.9\text{ V to } \pm 2.75\text{ V})^{(1)}$

at $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFFSET VOLTAGE						
V_{OS}	Input offset voltage			0.75	4.5	mV
dV_{OS}/dT	V_{OS} vs temperature	$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		2		$\mu\text{V}/^\circ\text{C}$
PSRR	Power-supply rejection ratio			86		dB
INPUT BIAS CURRENT						
I_B	Input bias current	$T_A = 25^\circ\text{C}$		± 1		pA
I_{OS}	Input offset current			± 1		pA
INPUT IMPEDANCE						
Z_{ID}	Differential			$100 \parallel 1$		$\text{M}\Omega \parallel \text{pF}$
Z_{IC}	Common-mode			$1 \parallel 5$		$10^{13}\Omega \parallel \text{pF}$
INPUT VOLTAGE RANGE						
V_{CM}	Common-mode voltage range	No phase reversal, rail-to-rail input	$(V-) - 0.2$		$(V+) + 0.2$	V
CMRR	Common-mode rejection ratio	$V_{CM} = -0.2\text{ V to } 5.7\text{ V}$	60	76		dB
OPEN-LOOP GAIN						
A_{OL}	Open-loop voltage gain	$0.3\text{ V} < V_O < (V+) - 0.3\text{ V}$, $R_L = 2\text{ k}\Omega$	90	110		
	Phase margin	$V_S = 5\text{ V}$, $G = 1$		65		°
OUTPUT						
V_O	Voltage output swing from supply rails	$R_L = 100\text{ k}\Omega$		5		mV
		$R_L = 2\text{ k}\Omega$		75	100	
I_{SC}	Short-circuit current			± 15		mA
R_O	Open-loop output impedance			2300		Ω
FREQUENCY RESPONSE						
GBW	Gain-bandwidth product			1		MHz
SR	Slew rate			0.5		V/ μs
t_S	Settling time	To 0.1%, $V_S = 5\text{ V}$, 2-V step, $G = +1$		5		μs
NOISE						
	Input voltage noise (peak-to-peak)	$f = 0.1\text{ Hz to } 10\text{ Hz}$		6		μV_{PP}
e_n	Input voltage noise density	$f = 1\text{ kHz}$		28		$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input current noise density	$f = 1\text{ kHz}$		5		$\text{fA}/\sqrt{\text{Hz}}$
POWER SUPPLY						
V_S	Specified voltage range		1.8 (± 0.9)		5.5 (± 2.75)	V
I_Q	Quiescent current per amplifier	$I_O = 0\text{ mA}$, $V_S = 5\text{ V}$		75	100	μA
	Power-on time	$V_S = 0\text{ V to } 5\text{ V}$, to 90% I_Q level		10		μs

- (1) Parameters with minimum or maximum specification limits are 100% production tested at 25°C , unless otherwise noted. Overtemperature limits are based on characterization and statistical analysis.

6.7 Typical Characteristics: Table of Graphs

表 1. Table of Graphs

TITLE	FIGURE
Open-Loop Gain and Phase vs Frequency	Figure 1
Quiescent Current vs Supply Voltage	Figure 2
Offset Voltage Production Distribution	Figure 3
Offset Voltage vs Common-Mode Voltage (Maximum Supply)	Figure 4
CMRR and PSRR vs Frequency (RTI)	Figure 5
0.1-Hz to 10-Hz Input Voltage Noise (5.5 V)	Figure 6
Input Voltage Noise Spectral Density vs Frequency (1.8 V, 5.5 V)	Figure 7
Input Bias and Offset Current vs Temperature	Figure 8
Open-Loop Output Impedance vs Frequency	Figure 9
Maximum Output Voltage vs Frequency and Supply Voltage	Figure 10
Output Voltage Swing vs Output Current	Figure 11
Closed-Loop Gain vs Frequency, $G = 1, -1, 10$ (1.8 V)	Figure 12
Small-Signal Step Response, Noninverting (1.8 V)	Figure 13
Small-Signal Step Response, Noninverting (5.5 V)	Figure 14
Large-Signal Step Response, Noninverting (1.8 V)	Figure 15
Large-Signal Step Response, Noninverting (5.5 V)	Figure 16
No Phase Reversal	Figure 17
EMIRR IN+ vs Frequency	Figure 18

6.8 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$ (unless otherwise noted)

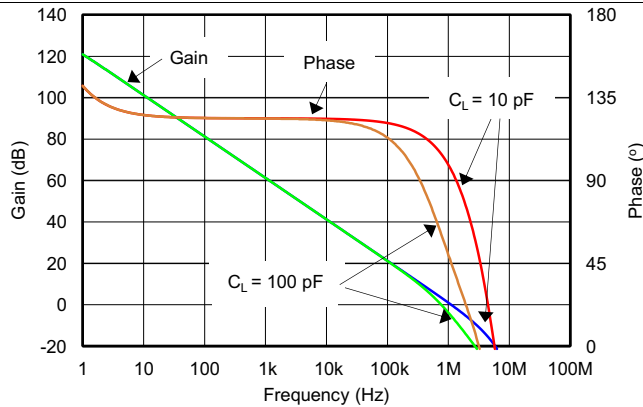


图 1. Open-Loop Gain and Phase vs Frequency

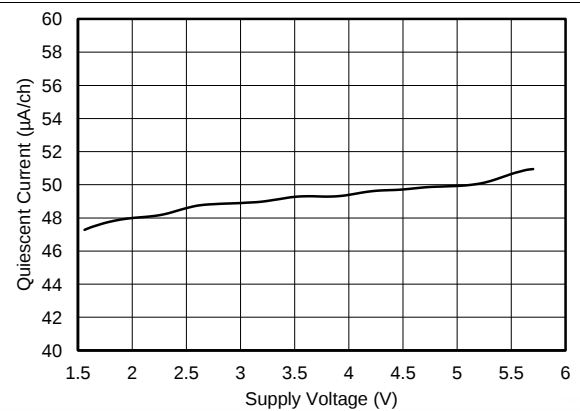


图 2. Quiescent Current vs Supply

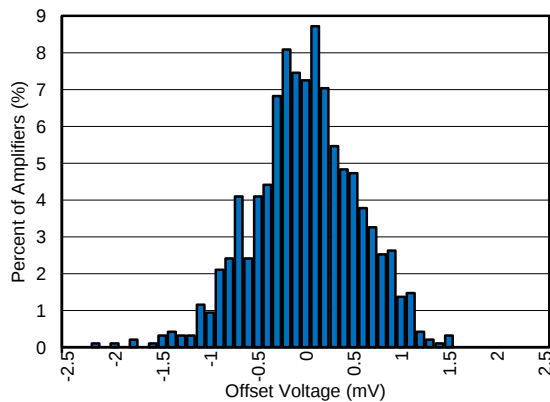


图 3. Offset Voltage Production Distribution

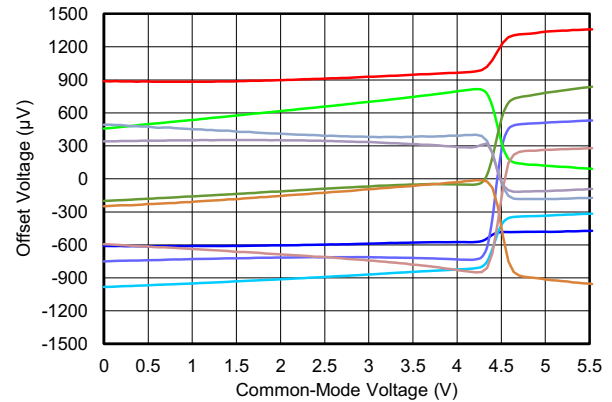


图 4. Offset Voltage vs Common-Mode Voltage

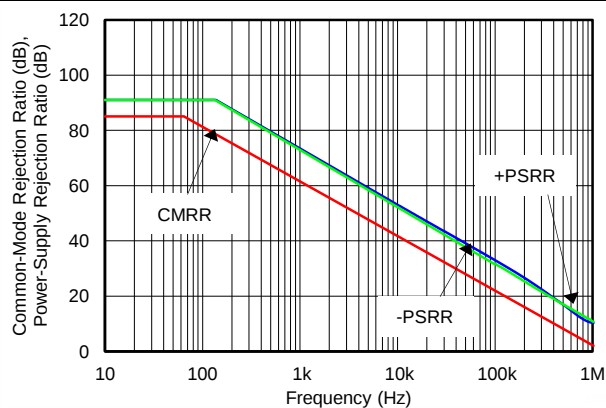


图 5. CMRR and PSRR vs Frequency (Referred-to-Input)

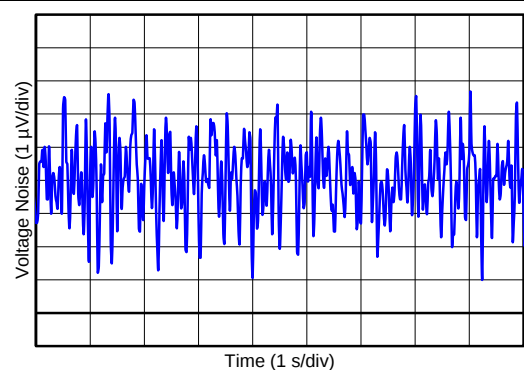


图 6. 0.1-Hz to 10-Hz Input Voltage Noise

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$ (unless otherwise noted)

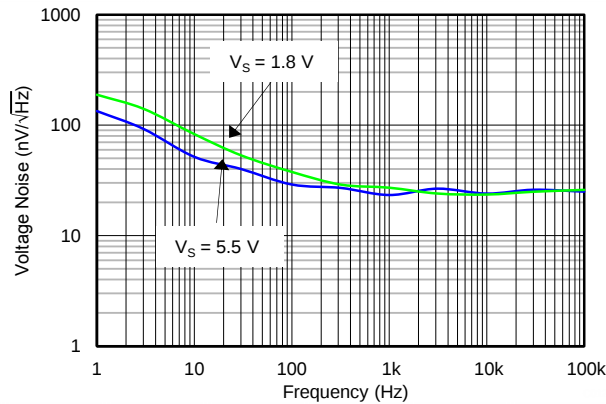


FIG 7. Input Voltage Noise Spectral Density vs Frequency

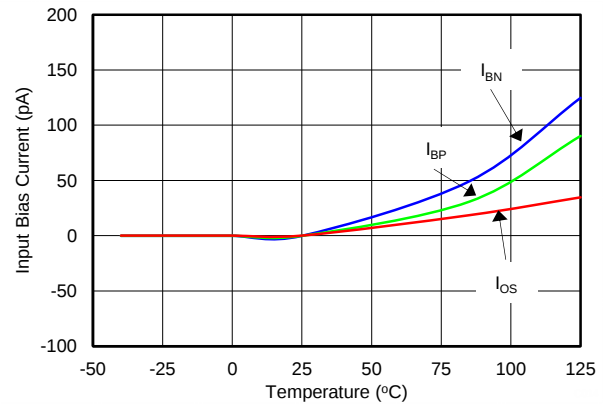


FIG 8. Input Bias and Offset Current vs Temperature

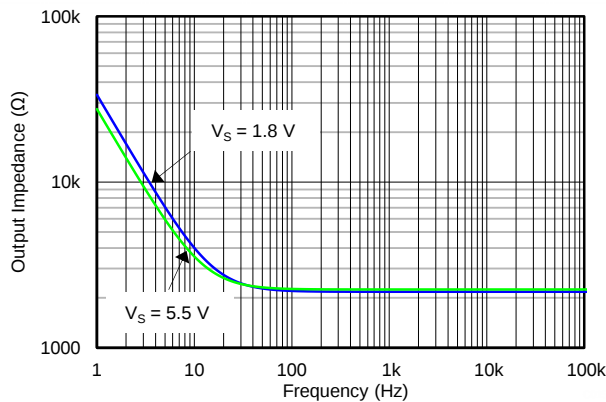


FIG 9. Open-Loop Output Impedance vs Frequency

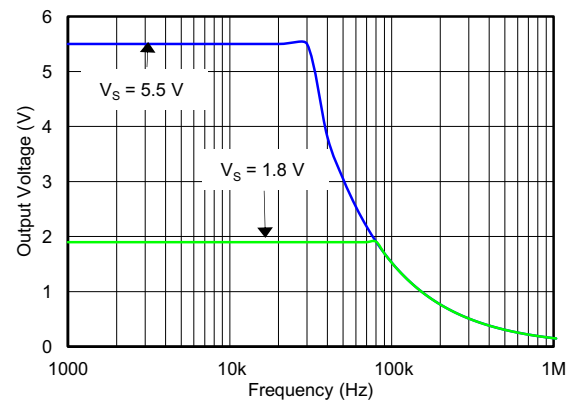


FIG 10. Maximum Output Voltage vs Frequency and Supply Voltage

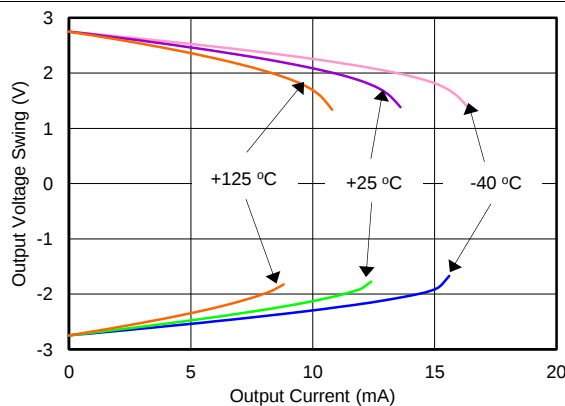


FIG 11. Output Voltage Swing vs Output Current

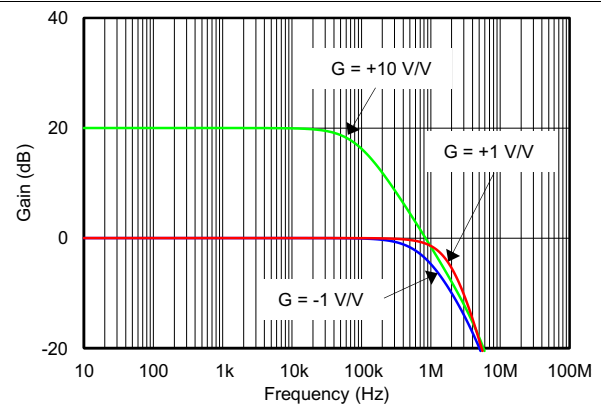


FIG 12. Closed-Loop Gain vs Frequency (Minimum Supply)

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$ (unless otherwise noted)

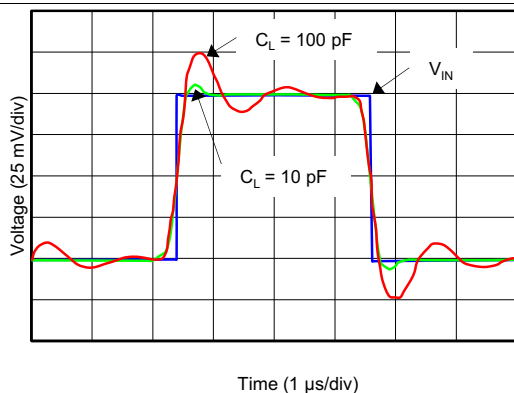


FIG 13. Small-Signal Pulse Response (Minimum Supply)

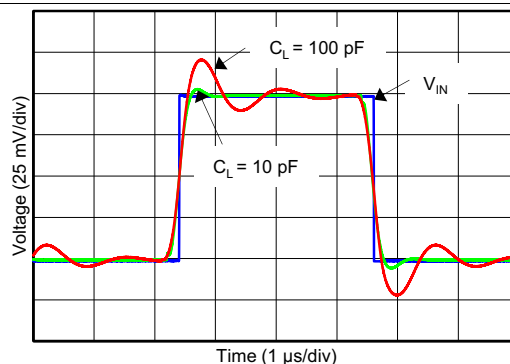


FIG 14. Small-Signal Pulse Response (Maximum Supply)

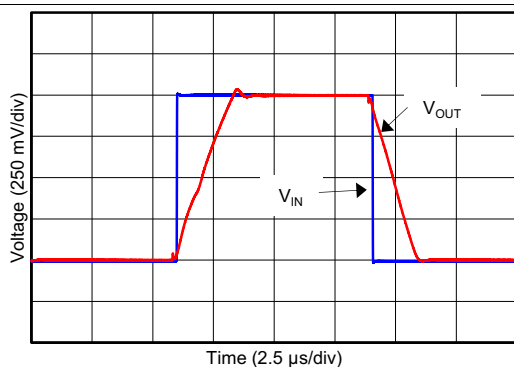


FIG 15. Large-Signal Pulse Response (Minimum Supply)

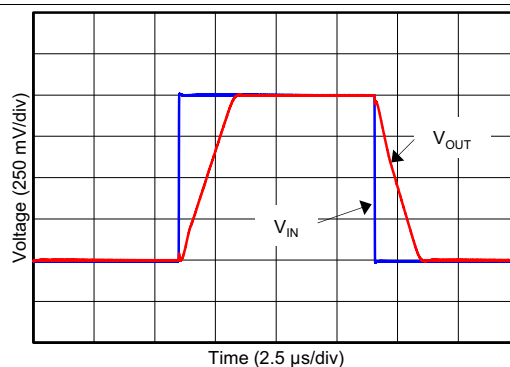


FIG 16. Large-Signal Pulse Response (Maximum Supply)

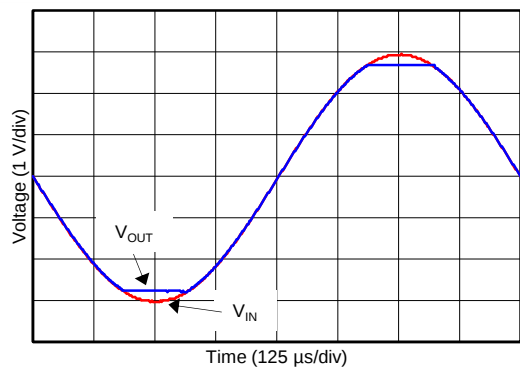


FIG 17. No Phase Reversal

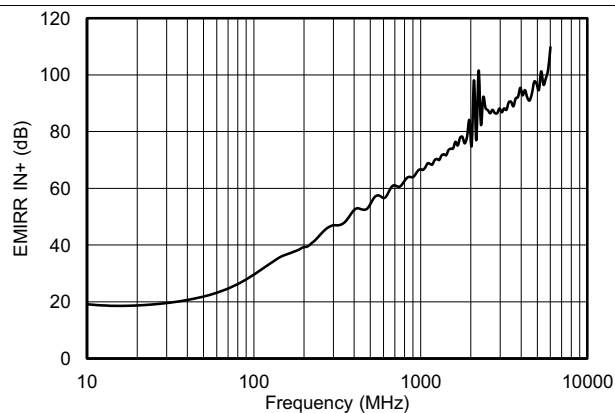


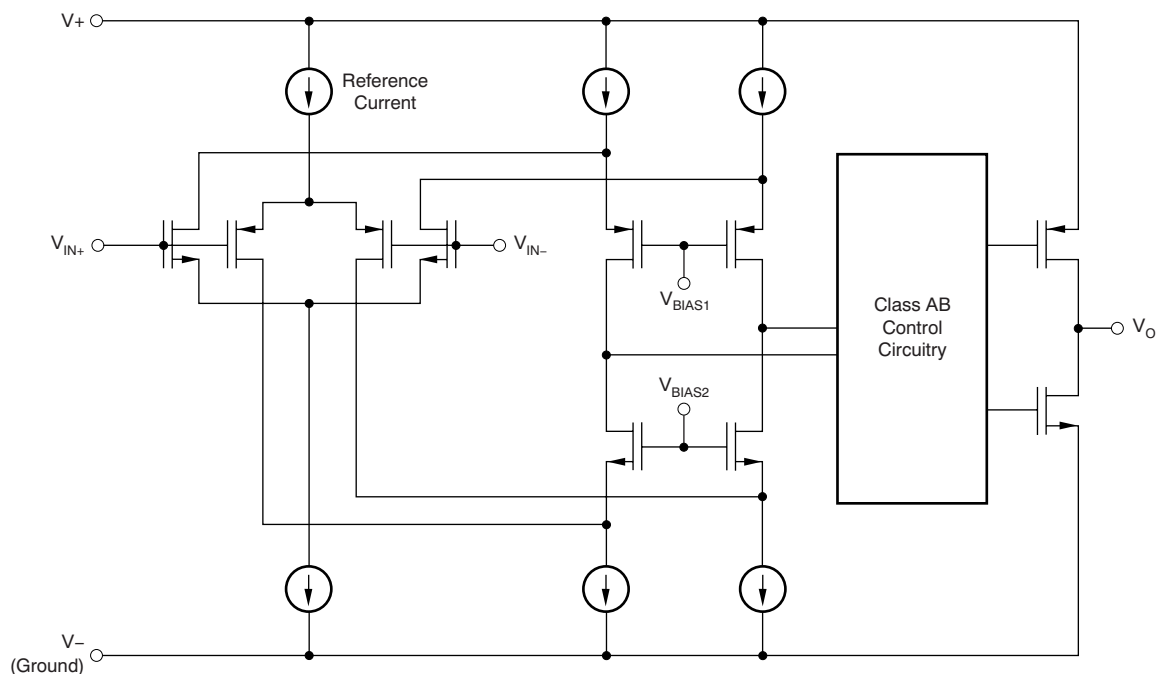
FIG 18. EMIRR IN+ vs Frequency

7 Detailed Description

7.1 Overview

The TLV600x-Q1 family of operational amplifiers is a general-purpose, low-cost family that is designed for a wide range of portable applications. Rail-to-rail input and output swings, low quiescent current, and wide dynamic range make the operational amplifier designed to drive sampling analog-to-digital converters (ADCs) and other single-supply applications.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Operating Voltage

The TLV600x-Q1 family is fully specified and tested from 1.8 V to 5.5 V (± 0.9 V to ± 2.75 V). The [Typical Characteristics](#) section shows parameters that vary with supply voltage.

7.3.2 Rail-to-Rail Input

The input common-mode voltage range of the TLV600x-Q1 family extends 200 mV beyond the supply rails. This performance is achieved with a complementary input stage: an N-channel input differential pair in parallel with a P-channel differential pair, as the [Functional Block Diagram](#) section shows. The N-channel pair is active for input voltages close to the positive rail, typically $(V+) - 1.3$ V to 200 mV above the positive supply, while the P-channel pair is on for inputs from 200 mV below the negative supply to approximately $(V+) - 1.3$ V. There is a small transition region, typically $(V+) - 1.4$ V to $(V+) - 1.2$ V, in which both pairs are on. This 200-mV transition region can vary up to 300 mV with process variation. As a result, the transition region (both stages on) can range from $(V+) - 1.7$ V to $(V+) - 1.5$ V on the low end, and up to $(V+) - 1.1$ V to $(V+) - 0.9$ V on the high end. Within this transition region, PSRR, CMRR, offset voltage, offset drift, and THD can degrade compared to device operation outside this region.

7.3.3 Rail-to-Rail Output

Designed as a micro-power, low-noise operational amplifier, the TLV600x-Q1 family delivers a robust output drive capability. A class AB output stage with common source transistors achieve full rail-to-rail output swing capability. For resistive loads up to 100 k Ω , the output swings typically to within 5 mV of either supply rail regardless of the power supply voltage that is applied. [Figure 11](#) shows that different load conditions change the ability of the amplifier to swing close to the rails.

7.3.4 Common-Mode Rejection Ratio (CMRR)

CMRR for the TLV600x-Q1 family is specified in several ways so the best match for a given application can be used; see the [Electrical Characteristics](#). First, the CMRR of the device in the common-mode range below the transition region ($V_{CM} < (V+) - 1.3$ V) is shown. This specification is the best indicator of the capability of the device when the application requires the use of one of the differential input pairs. Second, the CMRR over the entire common-mode range is specified at $(V_{CM} = -0.2$ V to 5.7 V). This last value includes the variations seen through the transition region, as [Figure 4](#) shows.

7.3.5 Capacitive Load and Stability

The TLV600x-Q1 family is designed to be used in applications where driving a capacitive load is required. As with all operational amplifiers, there can be specific instances where the TLV600x-Q1 family can become unstable. The particular op amp circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing if an amplifier is stable in operation. An operational amplifier in the unity-gain (1-V/V) buffer configuration that drives a capacitive load exhibits a greater tendency for instability than an amplifier that is operated at a higher noise gain. The capacitive load in conjunction with the op amp output resistance creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases. When operating in the unity-gain configuration, the TLV600x-Q1 family remains stable with a pure capacitive load up to approximately 1 nF. The equivalent series resistance (ESR) of some capacitors (C_L greater than 1 μ F) is sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when observing the overshoot response of the amplifier at higher voltage gains.

Feature Description (continued)

One technique for increasing the capacitive load drive capability of the amplifier when the device operates in a unity-gain configuration is to insert a small resistor, typically $10\ \Omega$ to $20\ \Omega$, in series with the output, as [Figure 19](#) shows. This resistor reduces the overshoot and ringing associated with large capacitive loads. One possible problem with this technique is that a voltage divider is created with the added series resistor and any resistor connected in parallel with the capacitive load. The voltage divider introduces a gain error at the output that reduces the output swing.

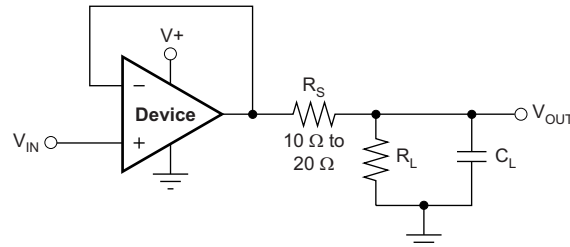


Figure 19. Improving Capacitive Load Drive

7.3.6 EMI Susceptibility and Input Filtering

Operational amplifiers vary with regard to the susceptibility of the device to electromagnetic interference (EMI). If conducted EMI enters the op amp, the dc offset observed at the amplifier output can shift from the nominal value while EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. While all op amp pin functions can be affected by EMI, the signal input pins are likely to be the most susceptible. The TLV600x-Q1 family incorporates an internal input low-pass filter that reduces the amplifiers response to EMI. This filter provides common-mode and differential mode filtering. The filter is designed for a cutoff frequency of approximately 35 MHz (–3 dB) with a rolloff of 20 dB per decade.

Texas Instruments developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. The EMI rejection ratio (EMIRR) metric allows op amps to be directly compared by the EMI immunity. [Figure 18](#) shows the results of this testing on the TLV600x-Q1 family. [EMI Rejection Ratio of Operational Amplifiers](#) shows detailed information, and is available for download from www.ti.com.

7.4 Device Functional Modes

The TLV600x-Q1 family has a single functional mode. The device is powered on if the power-supply voltage is between 1.8 V (± 0.9 V) and 5.5 V (± 2.75 V).

7.5 Input and ESD Protection

The TLV600x-Q1 family incorporates internal electrostatic discharge (ESD) protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current-steering diodes connected between the input and power supply pins. The ESD protection diodes provide in-circuit, input overdrive protection if the current is limited to 10 mA, as the [Absolute Maximum Ratings](#) lists. [Figure 20](#) shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.

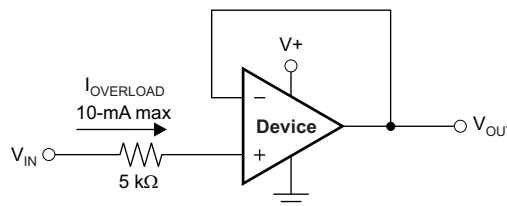


Figure 20. Input Current Protection

8 Application and Implementation

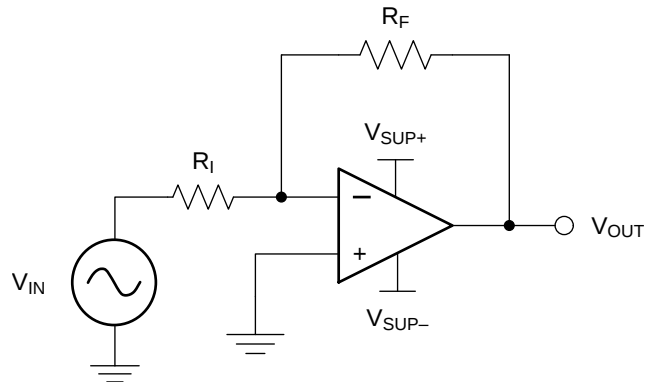
注

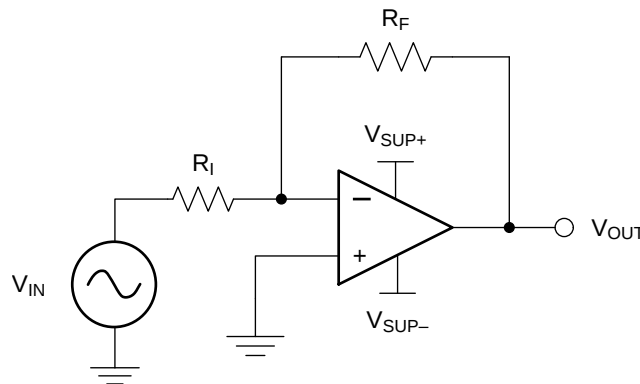
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TLV600x-Q1 is a low-power, rail-to-rail input and output operational amplifier specifically designed for portable applications. The device operates from 1.8 V to 5.5 V, is unity-gain stable, and is designed for a wide range of general-purpose applications. The class AB output stage can drive $\leq 10\text{-k}\Omega$ loads connected to any point between V_+ and ground. The input common-mode voltage range includes both rails and allows the TLV600x-Q1 family to be used in any single-supply application.

8.2 Typical Application

A typical application for an operational amplifier is an inverting amplifier, as  21 shows. An inverting amplifier takes a positive voltage on the input and outputs a signal inverted to the input, making a negative voltage of the same magnitude. In the same manner, the amplifier makes negative input voltages positive on the output. To add amplification, select an input resistor (R_I) and a feedback resistor (R_F).



 21. Application Schematic

8.2.1 Design Requirements

Select a supply voltage value that is larger than the input voltage range and the desired output range. Users must consider the limits of the input common-mode range (V_{CM}) and the output voltage swing to the rails (V_O). For example, this application scales a signal of $\pm 0.5\text{ V}$ (1 V) to $\pm 1.8\text{ V}$ (3.6 V). Setting the supply at $\pm 2.5\text{ V}$ is sufficient to accommodate this application.

8.2.2 Detailed Design Procedure

Use [式 1](#) and [式 2](#) to calculate the required gain for the inverting amplifier:

$$A_V = \frac{V_{OUT}}{V_{IN}} \quad (1)$$

$$A_V = \frac{1.8}{-0.5} = -3.6 \quad (2)$$

Typical Application (continued)

When the desired gain is determined, select a value for R_I or R_F . Selecting a value in the kilohm range is desirable for general-purpose applications because the amplifier circuit uses currents in the milliamp range. This milliamp current range ensures the device does not draw too much current. The trade-off is that large resistors (hundreds of kilohms) draw the smallest current but generate the highest noise. Small resistors (hundreds of ohms) generate low noise but draw high current. In this example, R_I equals 10 k Ω , and R_F equals 36 V. 式 3 determines these values:

$$A_V = -\frac{R_F}{R_I} \quad (3)$$

8.2.3 Application Curve

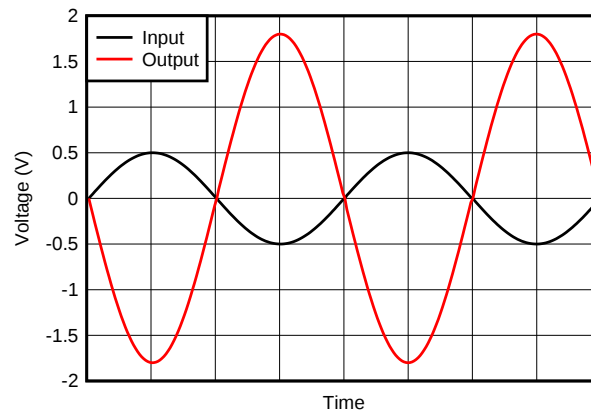
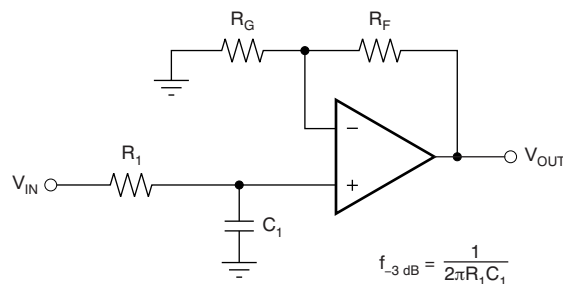


图 22. Inverting Amplifier Input and Output

8.3 System Examples

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. To establish this minimum bandwidth, place an RC filter at the noninverting pin of the amplifier, as 图 23 shows.



$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_IC_1}\right)$$

图 23. Single-Pole Low-Pass Filter

System Examples (continued)

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task, as [Figure 24](#) shows. For best results, the amplifier must have a bandwidth that is 8 to 10 times larger than the filter frequency bandwidth. Failure to follow this guideline can result in phase shift of the amplifier.

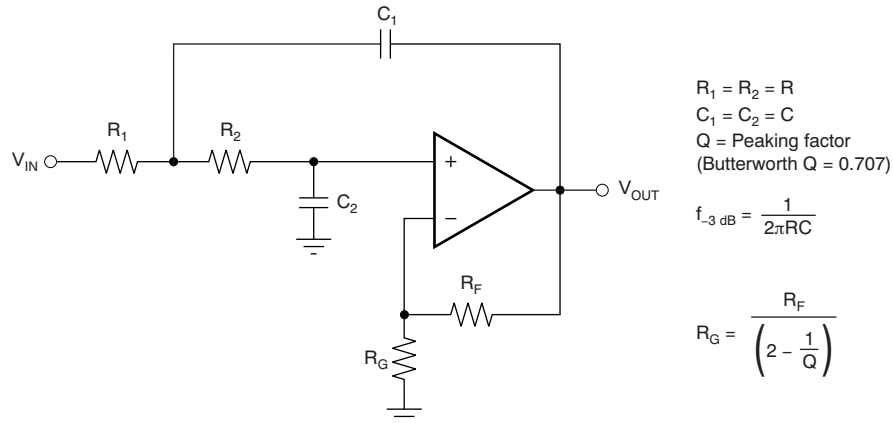


Figure 24. Two-Pole, Low-Pass, Sallen-Key Filter

9 Power Supply Recommendations

The TLV600x-Q1 family is specified for operation from 1.8 V to 5.5 V (± 0.9 V to ± 2.75 V). The [Typical Characteristics](#) section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

注意

Supply voltages larger than 7 V may permanently damage the device. (See the [Absolute Maximum Ratings](#)).

Place 0.1-μF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the [Layout Guidelines](#) section.

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit and the operational amplifier. Use bypass capacitors to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1- μ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are typically devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Take care to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, see [Circuit Board Layout Techniques](#) (available for download from www.ti.com).
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If the traces cannot be kept separate, crossing the sensitive trace perpendicularly is much better than crossing in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keep R_F and R_G close to the inverting input in order to minimize parasitic capacitance, as shown in [Figure 25](#).
- Keep the length of input traces as short as possible. Remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

10.2 Layout Example: Single Channel

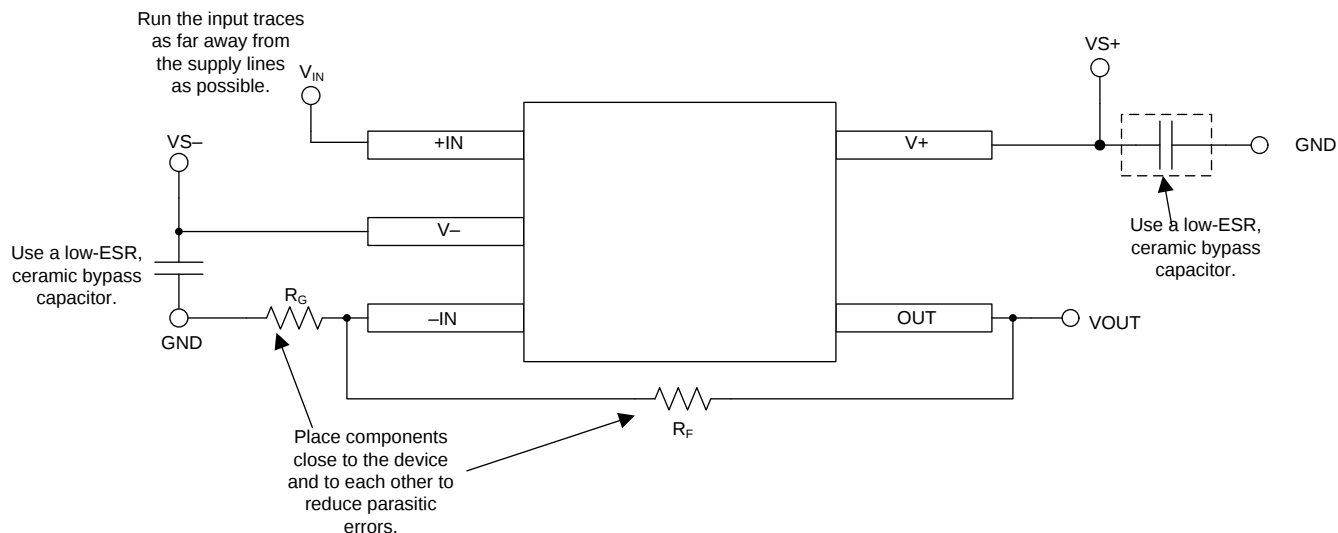


Figure 25. Operational Amplifier Board Layout for Noninverting Configuration

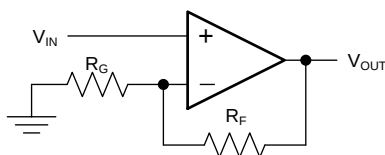


Figure 26. Schematic Representation of Figure 25

10.3 Layout Example: Dual Channel

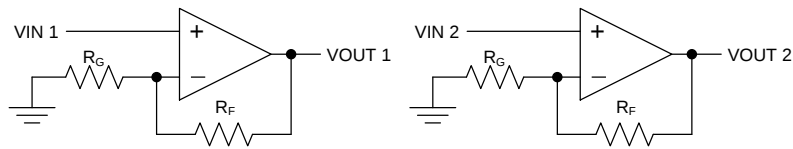


Figure 27. Schematic Representation for Figure 25

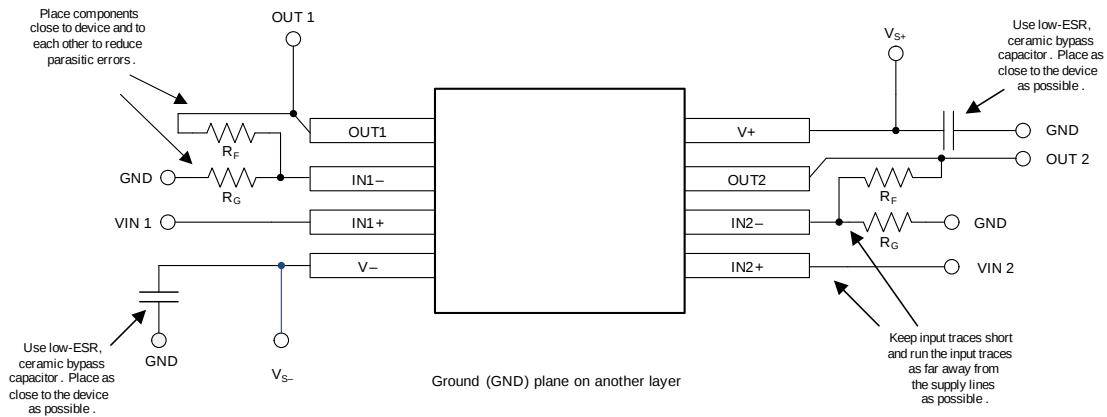


Figure 28. Layout Example

11 デバイスおよびドキュメントのサポート

11.1 ドキュメントのサポート

11.1.1 関連資料

関連資料については、以下を参照してください。

- テキサス・インスツルメンツ、『[オペアンプのEMI除去率](#)』
- テキサス・インスツルメンツ、『[回路基板のレイアウト技法](#)』

11.2 関連リンク

次の表に、クイック・アクセス・リンクを示します。カテゴリには、技術資料、サポートおよびコミュニティ・リソース、ツールとソフトウェア、およびご注文へのクイック・アクセスが含まれます。

表 2. 関連リンク

製品	プロダクト・フォルダ	ご注文はこちら	技術資料	ツールとソフトウェア	サポートとコミュニティ
TLV6001-Q1	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック
TLV6002-Q1	ここをクリック	ここをクリック	ここをクリック	ここをクリック	ここをクリック

11.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](#)のデバイス製品フォルダを開いてください。右上の「アラートを受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

11.4 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ オンライン・コミュニティ *TIのE2E (Engineer-to-Engineer)* コミュニティ。エンジニア間の共同作業を促進するために開設されたものです。e2e.ti.comでは、他のエンジニアに質問し、知識を共有し、アイデアを検討して、問題解決に役立てることができます。

設計サポート *TIの設計サポート* 役に立つE2Eフォーラムや、設計サポート・ツールをすばやく見つけることができます。技術サポート用の連絡先情報も参照できます。

11.5 商標

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.6 静電気放電に関する注意事項



すべての集積回路は、適切なESD保護方法を用いて、取扱いと保存を行うようにして下さい。

静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

11.7 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV6001QDCKRQ1	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1B1
TLV6001QDCKRQ1.B	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1B1
TLV6002QDGKRQ1	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1NX6
TLV6002QDGKRQ1.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	1NX6
TLV6002QDRQ1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	V6002Q
TLV6002QDRQ1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	V6002Q

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLV6001-Q1, TLV6002-Q1 :

- Catalog : [TLV6001](#), [TLV6002](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV6001QDCKRQ1	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
TLV6002QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV6002QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV6001QDCKRQ1	SC70	DCK	5	3000	183.0	183.0	20.0
TLV6002QDGKRQ1	VSSOP	DGK	8	2500	366.0	364.0	50.0
TLV6002QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0

DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

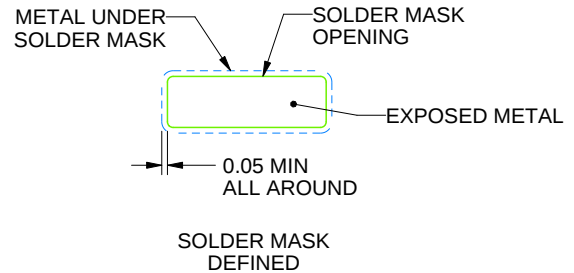
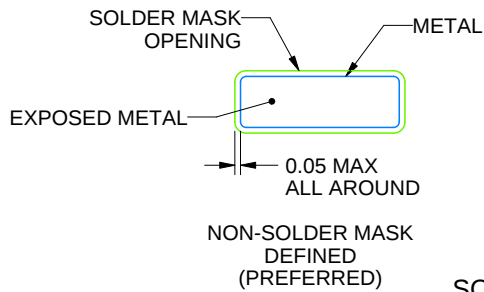
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.



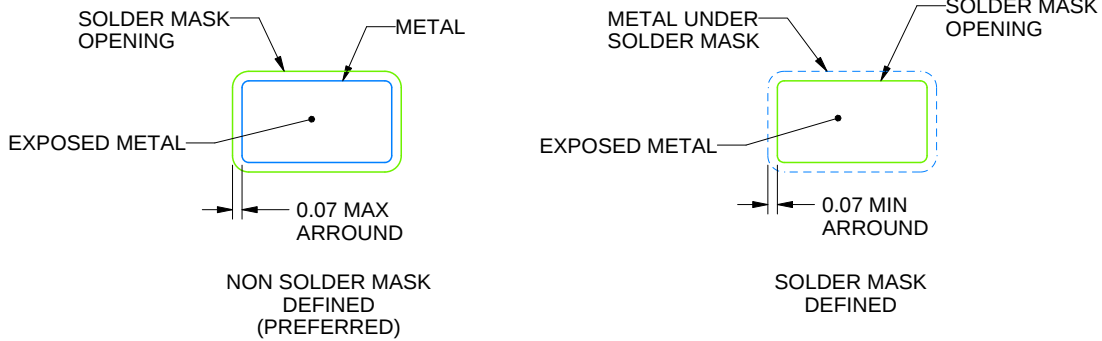
4214834/G 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

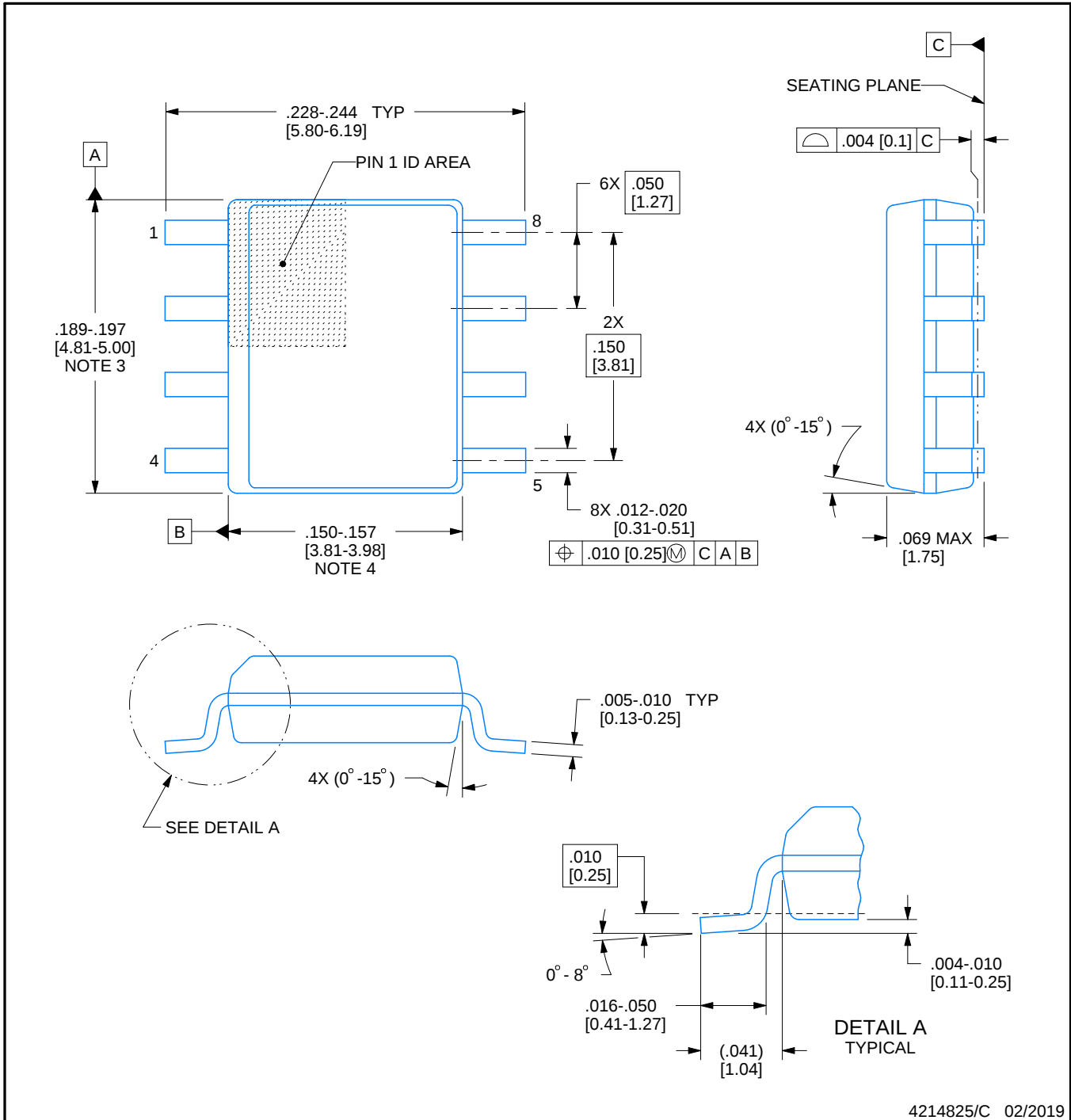


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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